

54AC191

Up/Down Counter with Preset and Ripple Clock

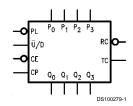
General Description

The 'AC191 is a reversible modulo 16 binary counter. It features synchronous counting and asynchronous presetting. The preset feature allows the 'AC191 to be used in programmable dividers. The Count Enable input, the Terminal Count output and the Ripple Clock output make possible a variety of methods of implementing multistage counters. In the counting modes, state changes are initiated by the rising edge of the clock.

Features

- I_{CC} reduced by 50%
- High speed 133 MHz typical count frequency
- Synchronous counting
- Asynchronous parallel load
- Cascadable
- Outputs source/sink 24 mA
- Standard Military Drawing (SMD)
 - 'AC191: 5962-89749

Logic Symbols

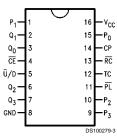


| CEE/EC | CTRDIV16 |

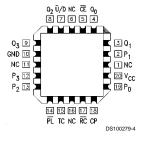
Pin Names	Description		
CE	Count Enable Input		
CP	Clock Pulse Input		
P ₀ -P ₃	Parallel Data Inputs		
PL	Asynchronous Parallel Load Input		
Ū/D	Up/Down Count Control Input		
Q_0-Q_3	Flip-Flop Outputs		
RC	Ripple Clock Output		
TC	Terminal Count Output		

Connection Diagrams

Pin Assignment for DIP and Flatpack



Pin Assignment for LCC



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Functional Description

The 'AC191 is a synchronous up/down counter. The 'AC191 is organized as a 4-bit binary counter. It contains four edge-triggered flip-flops with internal gating and steering logic to provide individual preset, count-up and count-down operations.

Each circuit has an asynchronous parallel load capability permitting the counter to be preset to any desired number. When the Parallel Load (\overline{PL}) input is LOW, information present on the Parallel Load inputs (P_0-P_3) is loaded into the counter and appears on the Q outputs. This operation overrides the counting functions, as indicated in the Mode Select Table.

A HIGH signal on the \overline{CE} input inhibits counting. When \overline{CE} is LOW, internal state changes are initiated synchronously by the LOW-to-HIGH transition of the clock input. The direction of counting is determined by the \overline{U}/D input signal, as indicated in the Mode Select Table. \overline{CE} and \overline{U}/D can be changed with the clock in either state, provided only that the recommended setup and hold times are observed.

Two types of outputs are provided as overflow/underflow indicators. The terminal count (TC) output is normally LOW. It goes HIGH when the circuits reach zero in the count down mode or 15 in the count up mode. The TC output will then remain HIGH until a state change occurs, whether by counting or presetting or until $\overline{\rm U}/{\rm D}$ is changed. The TC output should not be used as a clock signal because it is subject to decoding spikes

The TC signal is also used internally to enable the Ripple Clock (RC) output. The RC output is normally HIGH. When CE is LOW and TC is HIGH, RC output wil go LOW when the clock next goes LOW and will stay LOW until the clock goes HIGH again. This feature simplifies the design of multistage counters, as indicated in Figure 1 and Figure 2. In Figure 1, each RC output is used as the clock input for the next higher stage. This configuration is particularly advantageous when the clock source has a limited drive capability, since it drives only the first stage. To prevent counting in all stages it is only necessary to inhibit the first stage, since a HIGH signal on CE inhibits the RC output pulse, as indicated in the RC Truth Table. A disadvantage of this configuration, in some applications, is the timing skew between state changes in the first and last stages. This represents the cumulative delay of the clock as it ripples through the preceding stages.

A method of causing state changes to occur simultaneously in all stages is shown in $Figure\ 2.$ All clock inputs are driven in parallel and the \overline{RC} outputs propagate the carry/borrow signals in ripple fashion. In this configuration the LOW state duration of the clock must be long enough to allow the negative-going edge of the carry/borrow signal to ripple through to the last stage before the clock goes HIGH. There is no such restriction on the HIGH state duration of the clock, since the \overline{RC} output of any device goes HIGH shortly after its CP input goes HIGH.

The configuration shown in Figure 3 avoids ripple delays and their associated restrictions. The $\overline{\text{CE}}$ input for a given stage is formed by combining the TC signals from all the preceding stages. Note that in order to inhibit counting an enable signal must be included in each carry gate. The simple inhibit scheme of Figure 1 and Figure 2 doesn't apply, because the TC output of a given stage is not affected by its own $\overline{\text{CE}}$.

Mode Select Table

Inputs			Mode	
PL	CE	Ū/D	CP	
Н	L	L	~	Count Up
Н	L	Н	~	Count Down
L	X	X	X	Preset (Asyn.)
Н	Н	X	Х	No Change (Hold)

RC Truth Table

	Outputs			
PL	CE	TC*	CP	RC
Н	L	Н	T	7
Н	Н	X	Х	Н
Н	X	L	Х	Н
L	X	X	Х	Н

*TC is generated internally

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

^{✓ =} LOW-to-HIGH Transition

Functional Description (Continued)

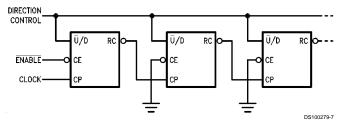


FIGURE 1. N-Stage Counter Using Ripple Clock

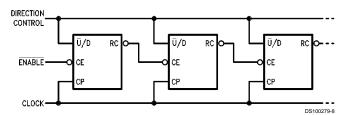


FIGURE 2. Synchronous N-Stage Counter Using Ripple Carry/Borrow

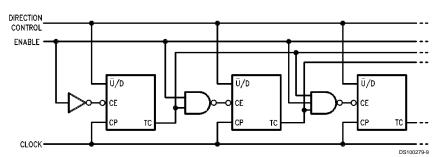
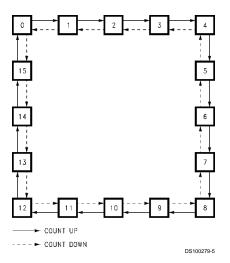
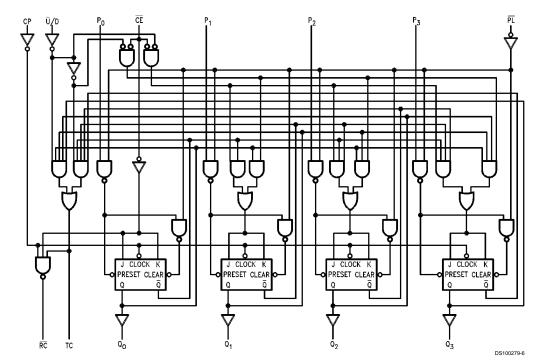


FIGURE 3. Synchronous N-Stage Counter with Parallel Gated Carry/Borrow

State Diagram



Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC}) = -0.5V to +7.0V

DC Input Diode Current (I_{IK})

 $\begin{array}{c} \rm V_I = -0.5V & -20~mA \\ \rm V_I = V_{CC} + 0.5V & +20~mA \\ \rm DC~Input~Voltage~(V_I) & -0.5V~to~V_{CC} + 0.5V \end{array}$

DC Output Diode Current (I_{OK})

or Sink Current (I_O)
DC V_{CC} or Ground Current

per Output Pin (I_{CC} or I_{GND}) ± 50 mA Storage Temperature (T_{STG}) -65° C to $+150^{\circ}$ C

Junction Temperature (T_J) CDIP

175°C

Recommended Operating Conditions

 $\begin{array}{lll} \mbox{Supply Voltage ($V_{\rm CC}$)} & 2.0 \mbox{V to } 6.0 \mbox{V} \\ \mbox{Input Voltage ($V_{\rm O}$)} & 0 \mbox{V to } \mbox{V}_{\rm CC} \\ \mbox{Output Voltage ($V_{\rm O}$)} & 0 \mbox{V to } \mbox{V}_{\rm CC} \\ \end{array}$

Operating Temperature (T_A)

54AC -55°C to +125°C

Minimum Input Edge Rate ($\Delta V/\Delta t$)

'AC Devices

±50 mA

 $\rm V_{IN}$ from 30% to 70% of $\rm V_{CC}$

V_{CC} @ 3.3V 4.5V, 5.5V 125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, output/input loading variables. National does not recommend operation of FACTTM circuits outside databook specifications.

DC Characteristics for 'AC Family Devices

	Parameter	.,	54AC		Conditions	
Symbol		V _{cc}	T _A = -55°C to +125°C	Units		
		(V)	Guaranteed Limits			
V _{IH}	Minimum High Level Input	3.0	2.1		V _{OUT} = 0.1V	
	Voltage	4.5	3.15	V	or V _{CC} – 0.1V	
		5.5	3.85			
V _{IL}	Maximum Low Level Input	3.0	0.9		V _{OUT} = 0.1V	
	Voltage	4.5	1.35	V	or V _{CC} – 0.1V	
		5.5	1.65			
V _{OH}	Minimum High Level Output	3.0	2.9		I _{OUT} = -50 μA	
	Voltage	4.5	4.4	V		
		5.5	5.4			
					(Note 2) V _{IN} = V _{IL} or V _{IH}	
		3.0	2.4		-12 mA	
		4.5	3.7	V	I _{OH} –24 mA	
		5.5	4.7		-24 mA	
V _{OL}	Maximum Low Level Output	3.0	0.1		I _{OUT} = 50 μA	
	Voltage	4.5	0.1	V		
		5.5	0.1			
					(Note 2) V _{IN} = V _{IL} or V _{IH}	
		3.0	0.50		12 mA	
		4.5	0.50	V	I _{OL} 24 mA	
		5.5	0.50		24 mA	
I _{IN}	Maximum Input	5.5	±1.0	μA	V _I = V _{CC} , GND	
	Leakage Current					
I _{OLD}	(Note 3) Minimum Dynamic	5.5	50	mA	V _{OLD} = 1.65V Max	
I _{OHD}	Output Current	5.5	-50	mA	V _{OHD} = 3.85V Min	
I _{cc}	Maximum Quiescent	5.5	80.0	μA	V _{IN} = V _{CC}	
	Supply Current				or GND	

DC Characteristics for 'AC Family Devices (Continued)

 $\textbf{Note 2:} \ \ \textbf{All outputs loaded; thresholds on input associated with output under test.}$

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC} . I_{CC} for 54AC @ 25°C is identical to 74AC @ 25°C.

AC Electrical Characteristics

		v	54AC T _A = -55°C to +125°C C _L = 50 pF		Units	
Symbol	Parameter	V _{cc} (V) (Note 5)				Fig. No.
			Min	Max	7	
f _{max}	Maximum Count	3.3	55		MHz	
	Frequency	5.0	80			
t _{PLH}	Propagation Delay	3.3	1.0	16.5	ns	
	CP to Q _n	5.0	1.0	12.0		
t _{PHL}	Propagation Delay	3.3	1.0	16.0	ns	
	CP to Q _n	5.0	1.0	12.0		
t _{PLH}	Propagation Delay	3.3	1.0	19.5	ns	
	CP to TC	5.0	1.0	14.0		
t _{PHL}	Propagation Delay	3.3	1.0	19.0	ns	
	CP to TC	5.0	1.0	14.5		
t _{PLH}	Propagation Delay	3.3	1.0	14.0	ns	
	CP to RC	5.0	1.0	10.5		
t _{PHL}	Propagation Delay	3.3	1.0	12.5	ns	
	CP to RC	5.0	1.0	9.5		
t _{PLH}	Propagation Delay	3.3	1.0	14.0	ns	
	CE to RC	5.0	1.0	10.0		
t _{PHL}	Propagation Delay	3.3	1.0	12.5	ns	
	CE to RC	5.0	1.0	9.5		
t _{PLH}	Propagation Delay	3.3	1.0	14.5	ns	
	Ū/D to RC	5.0	1.0	11.0		
t _{PHL}	Propagation Delay	3.3	1.0	15.0	ns	
	U/D to RC	5.0	1.0	11.0		
t _{PLH}	Propagation Delay	3.3	1.0	14.0	ns	
	U/D to TC	5.0	1.0	10.5		
t _{PHL}	Propagation Delay	3.3	1.0	13.5	ns	
	U/D to TC	5.0	1.0	10.0		
t _{PLH}	Propagation Delay	3.3	1.0	16.5	ns	
	P _n to Q _n	5.0	1.0	11.5		
t _{PHL}	Propagation Delay	3.3	1.0	15.5	ns	
	P _n to Q _n	5.0	1.0	10.5		
t _{PLH}	Propagation Delay	3.3	1.0	18.0	ns	
	PL to Q _n	5.0	1.0	12.5		
t _{PHL}	Propagation Delay	3.3	1.0	15.5	ns	
	PL to Q _n	5.0	1.0	11.5		

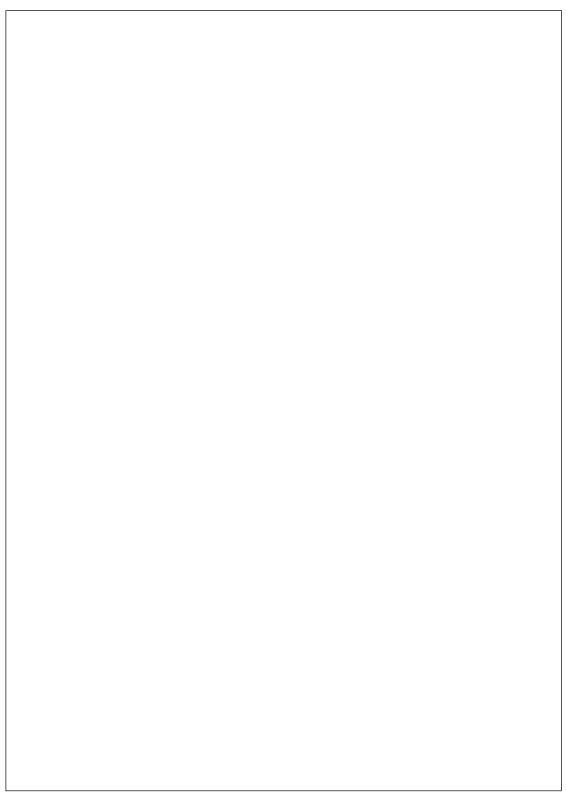
Note 5: Voltage Range 3.3 is 3.3V ±0.3V Voltage Range 5.0 is 5.0V ±0.5V

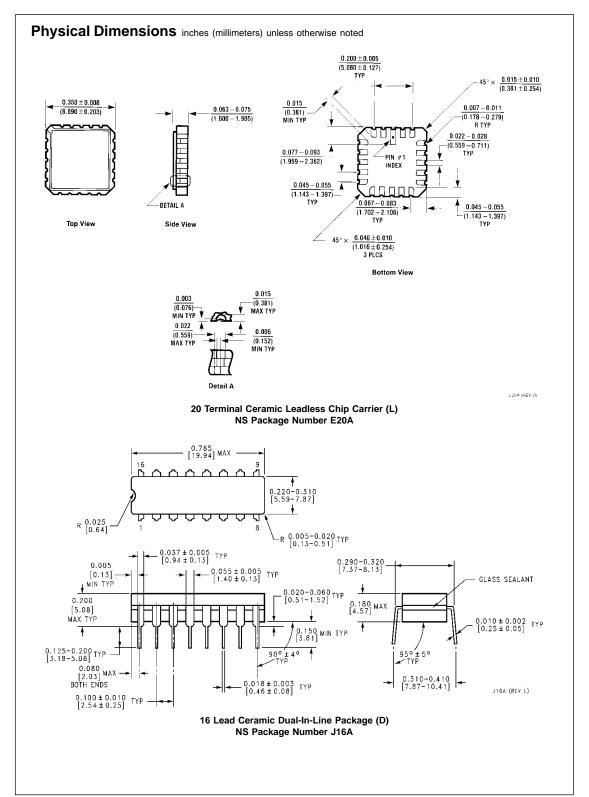
Symbol	Parameter	V _{cc} (V) (Note 6)	54AC T _A = -55°C to +125°C C _L = 50 pF	Units	Fig. No.
			Guaranteed Minimum		
t _s	Setup Time, HIGH or LOW	3.3	4.0	ns	
	P _n to $\overline{\text{PL}}$	5.0	3.0		
t _h	Hold Time, HIGH or LOW	3.3	1.5	ns	
	P _n to PL	5.0	2.0		
t _s	Setup Time, LOW	3.3	9.0	ns	
	CE to CP	5.0	6.0		
t _h	Hold Time, LOW	3.3	0	ns	
	CE to CP	5.0	0.5		
t _s	Setup Time, HIGH or LOW	3.3	10.5	ns	
	Ū/D to CP	5.0	7.5		
t _h	Hold Time, HIGH or LOW	3.3	0	ns	
	Ū/D to CP	5.0	1.0		
t _w	PL Pulse Width, LOW	3.3	5.0	ns	
		5.0	5.0		
t _w	CP Pulse Width, LOW	3.3	6.0	ns	
		5.0	6.0		
t _{rec}	Recovery Time	3.3	1.5	ns	
	PL to CP	5.0	1.0		

Note 6: Voltage Range 3.3 is 3.3V ±0.3V Voltage Range 5.0 is 5.0V ±0.5V

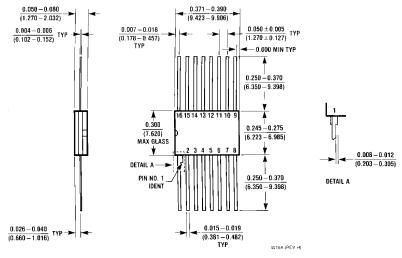
Capacitance

Symbol	Parameter	Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation	75.0	pF	V _{CC} = 5.0V
	Capacitance			





Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16 Lead Ceramic Flatpak (F) NS Package Number W16A

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